Low-power dual buffer/line driver; 3-state

Rev. 7 — 11 February 2013

Product data sheet

1. General description

The 74AUP2G241 provides a dual non-inverting buffer/line driver with 3-state outputs. The 3-state outputs are controlled by the output enable inputs $1\overline{OE}$ and 2OE. A HIGH level at pin $1\overline{OE}$ causes output 1Y to assume a high-impedance OFF-state. A LOW level at pin 2OE causes output 2Y to assume a high-impedance OFF-state.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This device has an input-disable feature, which allows floating input signals. The input 1A is disabled when the output enable input $1\overline{OE}$ is HIGH. The input 2A is disabled when the output enable input 2OE is LOW.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation

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- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Orderin	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G241DC	–40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP2G241GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm	SOT833-1
74AUP2G241GF	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 \times 1 \times 0.5 mm	SOT1089
74AUP2G241GD	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 3 \times 2 \times 0.5 mm	SOT996-2
74AUP2G241GM	–40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body $1.6 \times 1.6 \times 0.5$ mm	SOT902-2
74AUP2G241GN	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body $1.2 \times 1.0 \times 0.35$ mm	SOT1116
74AUP2G241GS	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 \times 1.0 \times 0.35 mm	SOT1203

4. Marking

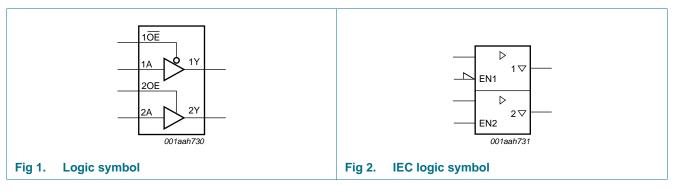
Table 2.Marking codes

Type number	Marking code ^[1]
74AUP2G241DC	p41
74AUP2G241GT	p41
74AUP2G241GF	р1
74AUP2G241GD	p41
74AUP2G241GM	p41
74AUP2G241GN	р1
74AUP2G241GS	р1

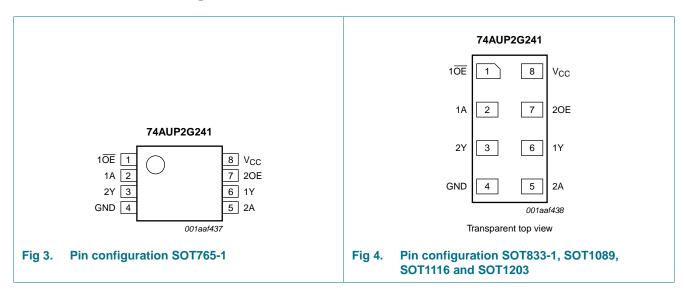
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

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5. Functional diagram



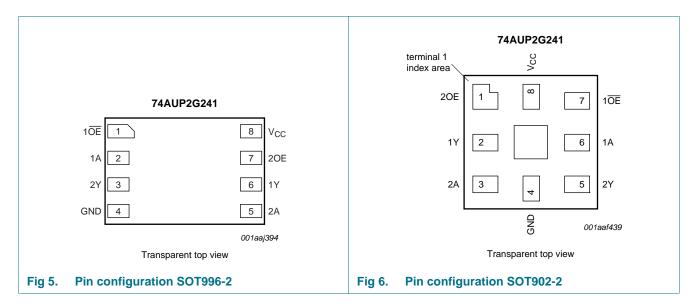
6. Pinning information



6.1 Pinning

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6.2 Pin description

Symbol	Pin		Description
	SOT765-1, SOT833-1, SOT1089, SOT996-2, SOT1116 and SOT1203	SOT902-2	
1 <mark>OE</mark>	1	7	output enable input $1\overline{OE}$ (active LOW)
1A, 2A	2, 5	6, 3	data input
1Y, 2Y	6, 3	2, 5	data output
GND	4	4	ground (0 V)
20E	7	1	output enable input 2OE (active HIGH)
V _{CC}	8	8	supply voltage

7. Functional description

Table 4. Function table^[1]

Input		Output	Input		Output
1 <mark>0E</mark>	1A	1Y	20E	2A	2Y
L	L	L	Н	L	L
L	Н	Н	Н	Н	Н
Н	Х	Z	L	Х	Z

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode	<u>[1]</u> –0.5	+4.6	V
lo	output current	$V_{O} = 0 V$ to V_{CC}	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$	[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For VSSOP8 packages: above 110 °C the value of Ptot derates linearly with 8.0 mW/K.

For XSON8 and XQFN8 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6.	Operating conditions				
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 0.8 V \text{ to } 3.6 V$	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V_{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL} I	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30\times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35\times V_{CC}$	V
	LOW-level input voltage	V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
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Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Uni
V _{он}	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		I_O = –20 $\mu\text{A};V_{CC}$ = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3\times V_{CC}$	V
		I_{O} = 1.7 mA; V_{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.44	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.44	V
I	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.1	μA
l _{oz}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
ΔI_{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μΑ
lcc	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \ \text{to} \ 3.6 \ V \end{array}$	-	-	0.5	μA
Δl _{CC}	additional supply current	data input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	<u>[1]</u> -	-	40	μΑ
		$1\overline{\text{OE}}$ and 2OE input; V _I = V _{CC} – 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	110	μA
		all inputs; $V_I = GND$ to 3.6 V; $1\overline{OE} = V_{CC}$; 2OE = GND; $V_{CC} = 0.8$ V to 3.6 V	[2] _	-	1	μA
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.6	-	pF
Co	output capacitance	output enabled; $V_0 = GND$; $V_{CC} = 0 V$	-	1.7	-	pF
		output disabled; V_{CC} = 0 V to 3.6 V; V_{O} = GND or V_{CC}	-	1.5	-	pF
T _{amb} = -	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	$0.70 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Uni
/ _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30\times V_{CC}$	V
		$V_{CC} = 0.9 \text{ V}$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
′он	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu\text{A};$ V_{CC} = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7 \times V_{CC}$	-	-	V
	LOW-level output voltage input leakage current power-off leakage current OFF-state output current	$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
/ _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
	input leakage current	$V_{I} = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μΑ
OFF	power-off leakage current	$V_{1} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.5	μΑ
OZ	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μA
IOFF	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μA
CC	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
Alcc	additional supply current	data input; V _I = V _{CC} – 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	<u>[1]</u> _	-	50	μA
		$1\overline{\text{OE}}$ and 2OE input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	<u>[1]</u> _	-	120	μA
		all inputs; $V_I = GND$ to 3.6 V; $1\overline{OE} = V_{CC}$; 2OE = GND; $V_{CC} = 0.8$ V to 3.6 V	[2] -	-	1	μΑ
amb = -	40 °C to +125 °C					
/ _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	$0.75\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6	-	-	V
		V_{CC} = 3.0 V to 3.6 V	2.0	-	-	V
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Table 7. Static characteristics ... continued

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Symbol	Parameter	Conditions	Min	Тур	Max	Uni
VIL	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.25 \times V_{CC}$	V
		$V_{CC} = 0.9 \text{ V} \text{ to } 1.95 \text{ V}$	-	-	$0.30\times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V _{он}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 0.8 \ \text{V} \ \text{to} \ 3.6 \ \text{V}$	$V_{CC}-0.11$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.6 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	0.93	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.17	-	-	V
		$I_0 = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.33 \times V_{CC}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.41	V
		I_{O} = 1.9 mA; V_{CC} = 1.65 V	-	-	0.39	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.36	V
		$I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.50	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.50	V
I	input leakage current	$V_{\rm I}$ = GND to 3.6 V; $V_{\rm CC}$ = 0 V to 3.6 V	-	-	±0.75	μΑ
OZ	OFF-state output current		-	-	±0.75	μA
OFF	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μΑ
∆l _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
СС	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \; A; \\ V_{CC} = 0.8 \; V \; \text{to} \; 3.6 \; V \end{array}$	-	-	1.4	μA
71 ^{CC}	additional supply current	data input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	<u>[1]</u> -	-	75	μΑ
		$1\overline{\text{OE}}$ and 2OE input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1] -	-	180	μΑ
		all inputs; $V_I = GND$ to 3.6 V; $1\overline{OE} = V_{CC}$; $2OE = GND$; $V_{CC} = 0.8$ V to 3.6 V	[2] -	-	1	μΑ

Table 7. Static characteristics ... continued

[1] One input at V_{CC} – 0.6 V, other input at $V_{CC} \mbox{ or GND}.$

[2] To show I_{CC} remains very low when the input-disable feature is enabled.

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11. Dynamic characteristics

Dynamic characteristics Table 8.

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +1	25 °C	Unit
				Min	Typ[1]	Мах	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 p	F									
t _{pd}	propagation delay	nA to nY; see Figure 7	[2]							
		$V_{CC} = 0.8 V$		-	20.6	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		2.8	5.5	10.5	2.5	11.7	12.9	ns
		V_{CC} = 1.4 V to 1.6 V		2.2	3.9	6.1	2.0	7.3	8.1	ns
		V_{CC} = 1.65 V to 1.95 V		1.9	3.2	4.8	1.7	6.1	6.7	ns
		V_{CC} = 2.3 V to 2.7 V		1.6	2.6	3.6	1.4	4.3	4.9	ns
		V_{CC} = 3.0 V to 3.6 V		1.4	2.4	3.1	1.2	3.9	4.4	ns
t _{en}	enable time	1OE to 1Y; see Figure 8	<u>[3]</u>							
		$V_{CC} = 0.8 V$		-	69.9	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		3.1	6.1	11.8	2.9	13.9	15.4	ns
		V_{CC} = 1.4 V to 1.6 V		2.5	4.2	6.6	2.3	7.7	8.3	ns
		V_{CC} = 1.65 V to 1.95 V		2.1	3.4	5.1	2.0	6.2	6.8	ns
		V_{CC} = 2.3 V to 2.7 V		1.8	2.6	3.7	1.7	4.5	5.0	ns
		V_{CC} = 3.0 V to 3.6 V		1.7	2.4	3.1	1.7	3.5	3.9	ns
		2OE to 2Y; see Figure 9	[3]							
		$V_{CC} = 0.8 V$		-	71.6	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		2.8	6.2	12.4	2.6	13.6	13.6	ns
		V_{CC} = 1.4 V to 1.6 V		2.3	4.2	6.9	2.2	7.4	7.7	ns
		V _{CC} = 1.65 V to 1.95 V		1.9	3.3	5.3	1.7	5.9	6.2	ns
		V_{CC} = 2.3 V to 2.7 V		1.5	2.4	3.6	1.4	3.8	4.1	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.3	2.0	2.9	1.2	3.2	3.4	ns
t _{dis}	disable time	1OE to 1Y; see Figure 8	<u>[4]</u>							
		V _{CC} = 0.8 V		-	14.3	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V		2.7	4.3	6.5	2.7	7.3	8.2	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.1	3.2	4.4	2.1	5.1	5.7	ns
		V _{CC} = 1.65 V to 1.95 V		2.0	3.0	4.3	2.0	5.0	5.7	ns
		V_{CC} = 2.3 V to 2.7 V		1.4	2.2	2.9	1.4	3.3	4.1	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	2.5	3.2	1.7	3.4	3.9	ns
		2OE to 2Y; see Figure 9	<u>[4]</u>							
		V _{CC} = 0.8 V		-	10.3	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.6	4.2	6.2	2.9	6.4	6.5	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2.1	3.2	4.4	2.2	4.6	4.7	ns
		$V_{CC} = 1.65$ V to 1.95 V		2.1	3.1	4.4	1.7	4.6	4.8	ns
		V _{CC} = 2.3 V to 2.7 V		1.7	2.4	3.2	1.4	3.4	3.6	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		2.1	2.8	3.6	1.2	3.7	3.8	ns

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +′	125 °C	Uni
				Min	Typ[1]	Мах	Min	Max (85 °C)	Max (125 °C)	
C _L = 10	ρF							•		
pd	propagation delay	nA to nY; see Figure 7	[2]							
		V _{CC} = 0.8 V		-	24.0	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V} \text{ to } 1.3 \text{ V}$		3.2	6.4	12.3	3.0	13.8	15.2	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.1	4.5	7.3	1.9	8.5	9.4	ns
		V _{CC} = 1.65 V to 1.95 V		1.9	3.8	5.5	1.7	6.8	7.6	ns
		V_{CC} = 2.3 V to 2.7 V		2.1	3.2	4.2	1.6	5.3	5.9	ns
		V_{CC} = 3.0 V to 3.6 V		1.8	3.0	3.8	1.6	4.6	5.2	ns
en	enable time	1OE to 1Y; see Figure 8	[3]							
		V _{CC} = 0.8 V		-	73.7	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		3.6	6.9	13.5	3.4	15.8	17.5	ns
		V_{CC} = 1.4 V to 1.6 V		2.3	4.8	7.7	2.2	8.6	9.4	ns
		V_{CC} = 1.65 V to 1.95 V		2.0	3.9	5.8	1.9	6.8	7.4	ns
		V_{CC} = 2.3 V to 2.7 V		1.8	3.2	4.3	1.7	5.3	5.9	ns
		V_{CC} = 3.0 V to 3.6 V		1.7	3.0	3.9	1.7	4.3	4.8	ns
		2OE to 2Y; see Figure 9	[3]							
		$V_{CC} = 0.8 V$		-	75.3	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		3.2	7.1	14.1	3.0	15.4	15.4	ns
		V_{CC} = 1.4 V to 1.6 V		2.2	4.8	8.0	2.1	8.3	8.6	ns
		V_{CC} = 1.65 V to 1.95 V		1.8	3.9	5.9	1.7	6.5	6.8	ns
		V_{CC} = 2.3 V to 2.7 V		1.5	2.9	4.2	1.4	4.5	4.8	ns
		V_{CC} = 3.0 V to 3.6 V		1.4	2.6	3.6	1.3	3.8	4.0	ns
dis	disable time	1OE to 1Y; see Figure 8	<u>[4]</u>							
		$V_{CC} = 0.8 V$		-	32.7	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V} \text{ to } 1.3 \text{ V}$		3.4	5.4	7.9	3.4	8.8	9.9	ns
		V_{CC} = 1.4 V to 1.6 V		2.2	4.1	5.5	2.2	6.2	7.1	ns
		V_{CC} = 1.65 V to 1.95 V		2.2	4.2	5.6	1.9	6.3	7.1	ns
		V_{CC} = 2.3 V to 2.7 V		1.7	3.0	3.8	1.7	4.5	5.1	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.1	3.8	4.8	1.7	5.0	5.6	ns
		2OE to 2Y; see Figure 9	[4]							
		$V_{CC} = 0.8 V$		-	12.2	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		3.5	5.3	7.6	3.3	7.9	7.9	ns
		V_{CC} = 1.4 V to 1.6 V		2.2	4.1	5.6	2.1	5.7	5.9	ns
		V_{CC} = 1.65 V to 1.95 V		2.4	4.2	5.7	1.7	5.8	6.0	ns
		V_{CC} = 2.3 V to 2.7 V		1.9	3.2	4.1	1.4	4.3	4.5	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.4	4.1	5.0	1.3	5.2	5.3	ns

Table 8. Dynamic characteristics ...continued

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions		25 °C		–40 °C to +125 °C			Unit	
				Min	Typ[1]	Мах	Min	Мах (85 °С)	Max (125 °C)	
C _L = 15 p	ρF									
t _{pd}	propagation delay	nA to nY; see Figure 7	[2]							
		$V_{CC} = 0.8 V$		-	27.4	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		3.6	7.2	14.1	3.3	15.8	17.5	ns
		V_{CC} = 1.4 V to 1.6 V		3.0	5.1	8.1	2.5	9.8	10.9	ns
		V_{CC} = 1.65 V to 1.95 V		2.2	4.3	6.3	2.0	7.9	8.8	ns
		V_{CC} = 2.3 V to 2.7 V		2.0	3.7	4.9	1.8	6.0	6.7	ns
		V_{CC} = 3.0 V to 3.6 V		2.0	3.5	4.4	1.8	5.4	6.1	ns
t _{en}	enable time	1OE to 1Y; see Figure 8	[3]							
		$V_{CC} = 0.8 V$		-	77.5	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		4.0	7.7	15.2	3.7	17.6	19.6	ns
		V_{CC} = 1.4 V to 1.6 V		3.0	5.3	8.4	2.5	9.8	10.7	ns
		V_{CC} = 1.65 V to 1.95 V		2.3	4.4	6.5	2.1	7.7	8.5	ns
		V_{CC} = 2.3 V to 2.7 V		2.1	3.6	5.0	2.0	6.1	6.8	ns
		V_{CC} = 3.0 V to 3.6 V		2.0	3.5	4.5	1.9	4.9	5.5	ns
		2OE to 2Y; see Figure 9	[3]							
		$V_{CC} = 0.8 V$		-	79.2	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		3.6	7.8	15.8	3.3	17.1	17.1	ns
		V_{CC} = 1.4 V to 1.6 V		3.0	5.4	8.8	2.9	9.4	9.7	ns
		V_{CC} = 1.65 V to 1.95 V		2.1	4.3	6.7	2.0	7.3	7.7	ns
		V_{CC} = 2.3 V to 2.7 V		1.8	3.4	4.8	1.7	5.2	5.6	ns
		V_{CC} = 3.0 V to 3.6 V		1.6	3.1	4.3	1.5	4.5	4.7	ns
dis	disable time	1OE to 1Y; see Figure 8	[4]							
		$V_{CC} = 0.8 V$		-	60.8	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		4.3	6.5	9.2	3.7	10.3	11.6	ns
		V_{CC} = 1.4 V to 1.6 V		3.0	5.0	6.5	2.5	7.4	8.4	ns
		V_{CC} = 1.65 V to 1.95 V		3.0	5.3	6.6	2.1	7.4	8.9	ns
		V_{CC} = 2.3 V to 2.7 V		2.1	3.8	4.9	2.0	5.1	6.4	ns
		V_{CC} = 3.0 V to 3.6 V		2.9	5.0	6.2	1.9	6.6	7.4	ns
		2OE to 2Y; see Figure 9	[4]							
		$V_{CC} = 0.8 V$		-	14.9	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.3	6.4	8.5	3.7	9.3	9.4	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.0	5.0	6.6	2.5	6.9	7.0	ns
		V_{CC} = 1.65 V to 1.95 V		3.1	5.4	6.6	2.0	7.4	7.5	ns
		V_{CC} = 2.3 V to 2.7 V		2.4	4.0	5.0	1.7	5.1	5.5	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		3.2	5.3	6.2	1.5	6.7	6.9	ns

Dynamic characteristics ... continued Table 8.

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions		25 °C		–40 °C to +125 °C			Unit	
				Min	Typ[1]	Мах	Min	Max (85 °C)	Max (125 °C)	
C _L = 30 p	ρF									
t _{pd}	propagation delay	nA to nY; see Figure 7	[2]							
		$V_{CC} = 0.8 V$		-	37.4	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		4.8	9.5	19.0	4.4	21.6	24.0	ns
		V_{CC} = 1.4 V to 1.6 V		4.0	6.7	10.8	3.0	13.0	14.5	ns
		V_{CC} = 1.65 V to 1.95 V		2.9	5.6	8.4	2.6	10.3	11.5	ns
		V_{CC} = 2.3 V to 2.7 V		2.7	4.8	6.3	2.5	7.8	8.7	ns
		V_{CC} = 3.0 V to 3.6 V		2.7	4.6	5.8	2.5	7.0	8.3	ns
t _{en}	enable time	1OE to 1Y; see Figure 8	[3]							
		$V_{CC} = 0.8 V$		-	88.9	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		5.2	9.9	19.8	4.8	22.8	25.3	ns
		V_{CC} = 1.4 V to 1.6 V		4.0	6.8	10.8	3.1	12.6	14.1	ns
		V_{CC} = 1.65 V to 1.95 V		3.0	5.6	8.5	2.8	10.2	11.3	ns
		V_{CC} = 2.3 V to 2.7 V		2.7	4.8	6.5	2.6	7.8	8.8	ns
		V_{CC} = 3.0 V to 3.6 V		2.7	4.6	6.0	2.6	6.9	7.7	ns
		2OE to 2Y; see Figure 9	[3]							
		$V_{CC} = 0.8 V$		-	90.6	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		4.7	10.0	20.4	4.3	22.0	22.0	ns
		V_{CC} = 1.4 V to 1.6 V		3.0	6.9	11.3	3.7	12.0	12.5	ns
		V_{CC} = 1.65 V to 1.95 V		2.6	5.6	8.6	3.2	9.5	10.1	ns
		V_{CC} = 2.3 V to 2.7 V		2.3	4.5	6.3	2.9	6.8	7.3	ns
		V_{CC} = 3.0 V to 3.6 V		2.2	4.2	5.8	2.7	6.4	6.7	ns
t _{dis}	disable time	1OE to 1Y; see Figure 8	[4]							
		$V_{CC} = 0.8 V$		-	49.9	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		6.0	9.9	13.3	4.8	14.8	16.5	ns
		V_{CC} = 1.4 V to 1.6 V		4.4	7.7	9.6	3.1	10.7	12.1	ns
		V_{CC} = 1.65 V to 1.95 V		5.1	8.7	11.1	2.8	12.4	13.8	ns
		V_{CC} = 2.3 V to 2.7 V		3.6	6.2	7.4	2.6	8.6	9.6	ns
		V_{CC} = 3.0 V to 3.6 V		5.2	8.7	10.5	2.6	10.8	13.1	ns
		2OE to 2Y; see Figure 9	[4]							
		$V_{CC} = 0.8 V$		-	51.6	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		6.0	9.8	13.6	4.7	14.3	14.4	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		4.5	7.7	10.5	3.0	10.7	11.0	ns
		V_{CC} = 1.65 V to 1.95 V		5.2	8.8	11.4	2.6	11.5	11.6	ns
		V_{CC} = 2.3 V to 2.7 V		3.9	6.4	7.4	2.3	9.0	10.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		5.5	9.0	10.7	2.2	10.8	12.0	ns

Dynamic characteristics ... continued Table 8.

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions		25 °C		-40	0 °C to +1	125 °C	Unit
			Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 p	F, 10 pF, 15 pF and	30 pF							
1 D	power dissipation capacitance	$f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [5]							
		$V_{CC} = 0.8 V$	-	2.8	-	-	-	-	pF
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	-	2.8	-	-	-	-	pF
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	3.0	-	-	-	-	pF
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	-	3.0	-	-	-	-	pF
		V_{CC} = 2.3 V to 2.7 V	-	3.7	-	-	-	-	pF
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V	-	4.2	-	-	-	-	рF

Table 8. Dynamic characteristics ... continued

[1] All typical values are measured at nominal V_{CC}.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] t_{en} is the same as t_{PZH} and t_{PZL} .

[4] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $\label{eq:PD} \mathsf{P}_\mathsf{D} = \mathsf{C}_\mathsf{PD} \times \mathsf{V}_\mathsf{CC}^2 \times \mathsf{f}_i \times \mathsf{N} + \Sigma(\mathsf{C}_\mathsf{L} \times \mathsf{V}_\mathsf{CC}^2 \times \mathsf{f}_o) \text{ where:}$

 f_i = input frequency in MHz;

 f_0 = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12. Waveforms

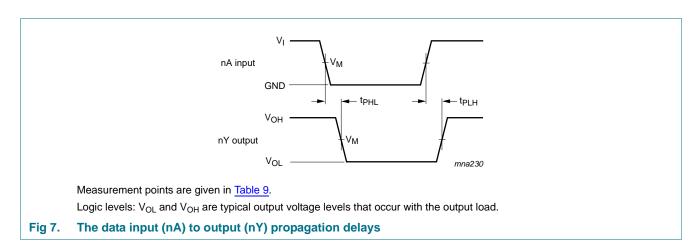


Table 9. **Measurement points**

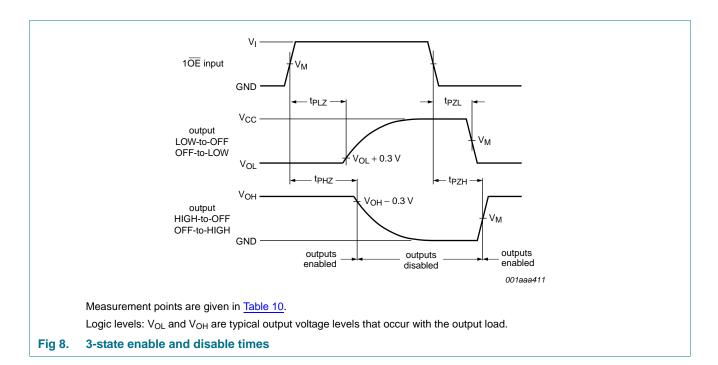
Supply voltage	Output	Input		
V _{CC}	V _M	V _M	VI	$\mathbf{t}_{r} = \mathbf{t}_{f}$
0.8 V to 3.6 V	$0.5 imes V_{CC}$	$0.5 imes V_{CC}$	V _{CC}	≤ 3.0 ns

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Low-power dual buffer/line driver; 3-state



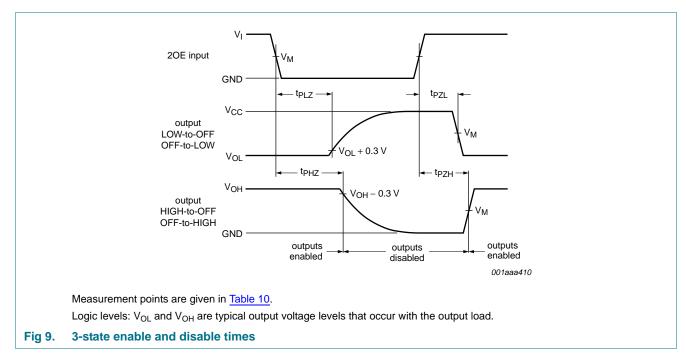


Table 10. Measurement points

Supply voltage	Input	Output		
V _{cc}	V _M	V _M	V _X	V _Y
0.8 V to 1.6 V	$0.5\times V_{CC}$	$0.5\times V_{CC}$	$V_{OL} + 0.1 V$	V _{OH} – 0.1 V
1.65 V to 2.7 V	$0.5\times V_{CC}$	$0.5\times V_{CC}$	V_{OL} + 0.15 V	V _{OH} – 0.15 V
3.0 V to 3.6 V	$0.5\times V_{CC}$	$0.5\times V_{CC}$	$V_{OL} + 0.3 V$	V _{OH} – 0.3 V

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Low-power dual buffer/line driver; 3-state

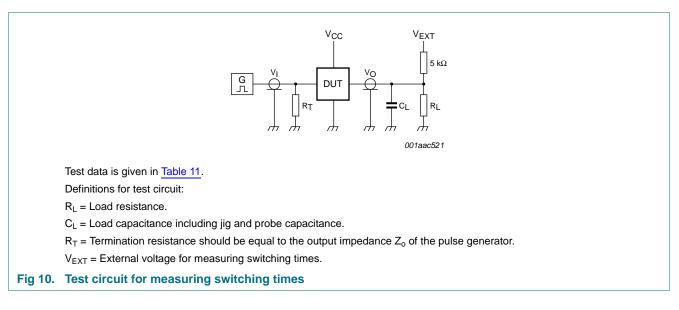


Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2\times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 M\Omega$.

Low-power dual buffer/line driver; 3-state

13. Package outline

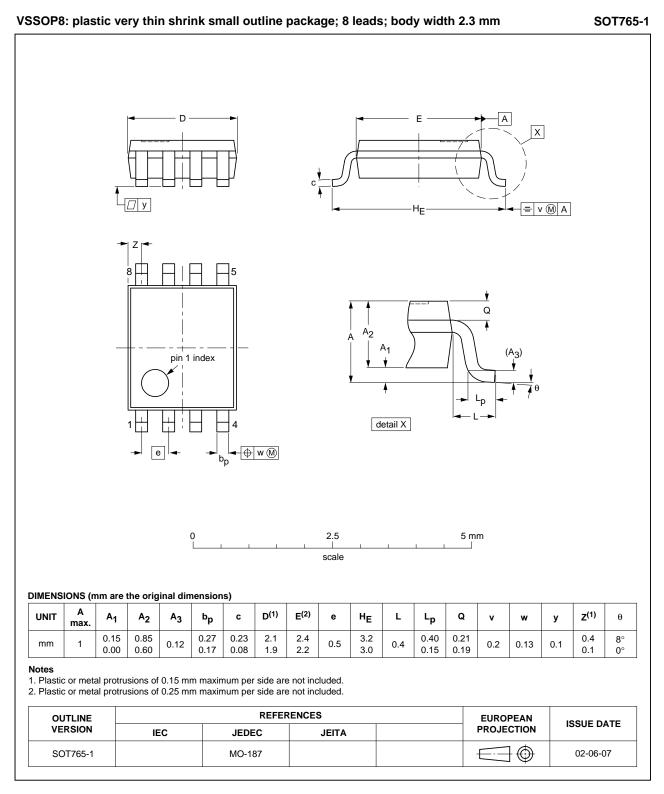


Fig 11. Package outline SOT765-1 (VSSOP8)

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Low-power dual buffer/line driver; 3-state

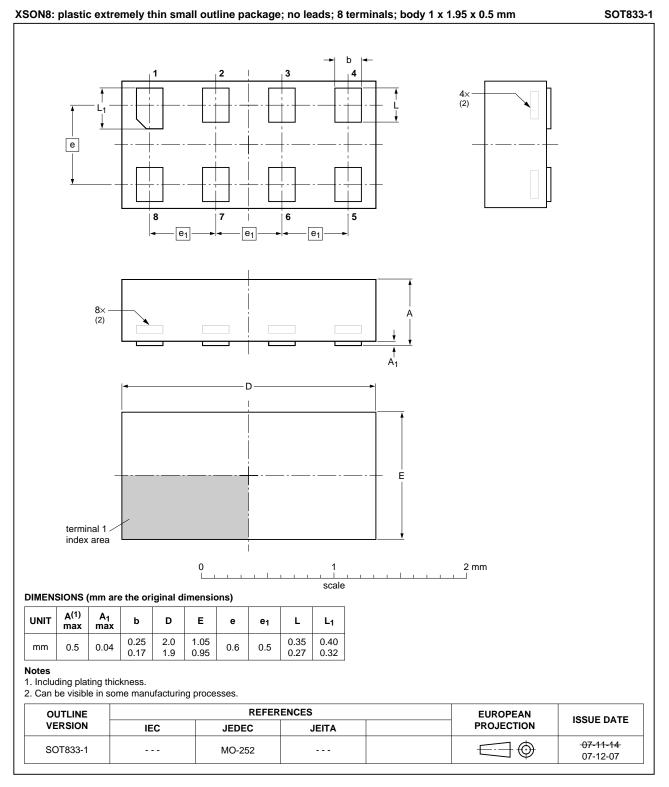
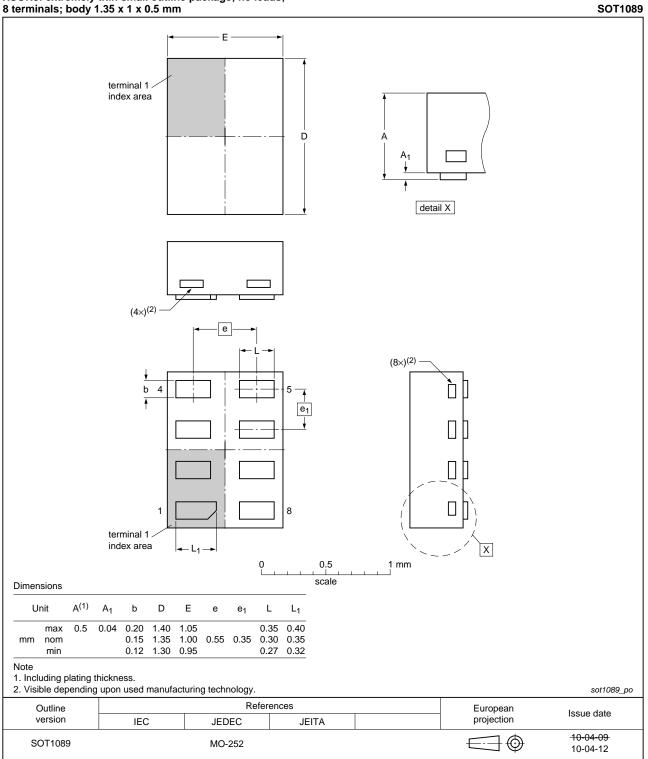


Fig 12. Package outline SOT833-1 (XSON8)

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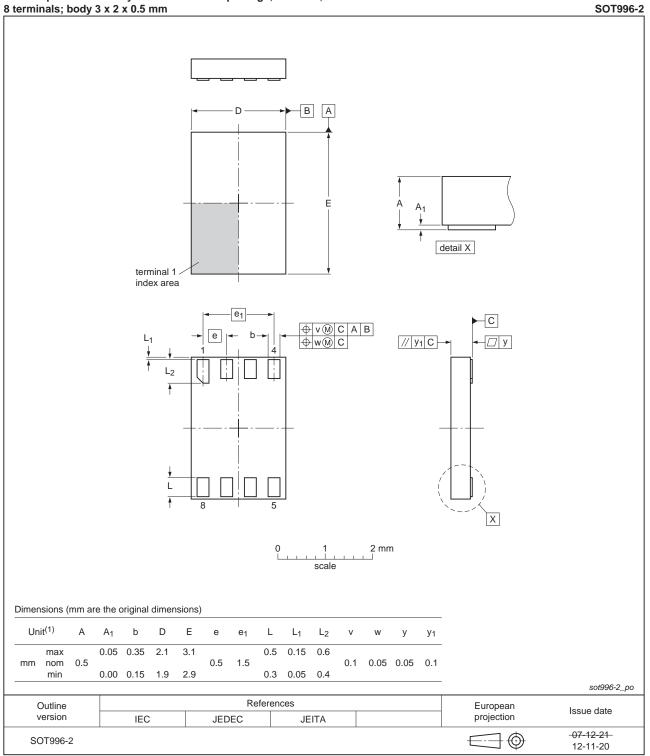
Low-power dual buffer/line driver; 3-state



XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm

Fig 13. Package outline SOT1089 (XSON8)

Low-power dual buffer/line driver; 3-state

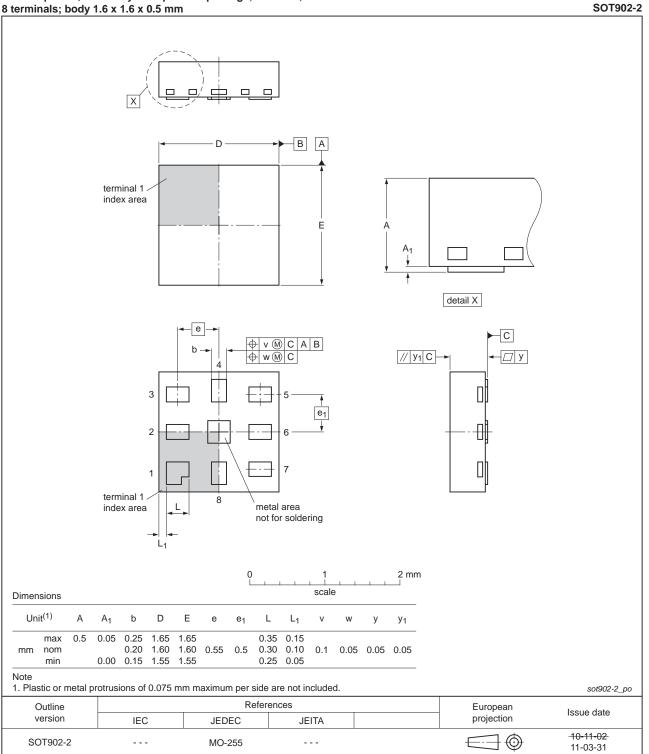


XSON8: plastic extremely thin small outline package; no leads;

Fig 14. Package outline SOT996-2 (XSON8)

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Low-power dual buffer/line driver; 3-state

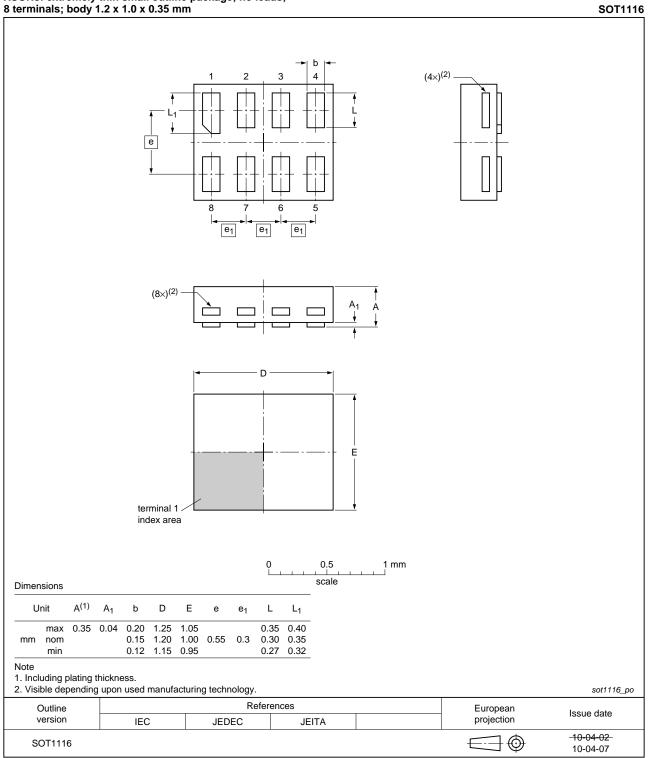


XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm

Fig 15. Package outline SOT902-2 (XQFN8)

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Low-power dual buffer/line driver; 3-state

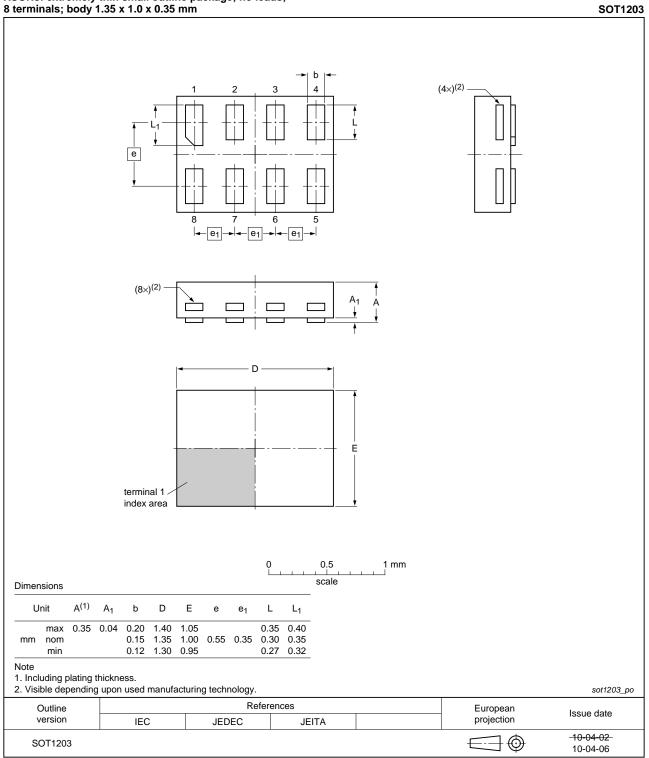


XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm

Fig 16. Package outline SOT1116 (XSON8)

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Low-power dual buffer/line driver; 3-state



XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm

Fig 17. Package outline SOT1203 (XSON8)

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Low-power dual buffer/line driver; 3-state

14. Abbreviations

Table 12. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			
MM	Machine Model			

15. Revision history

Table 13. Revision histo	ry			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP2G241 v.7	20130211	Product data sheet	-	74AUP2G241 v.6
Modifications:	 For type num 	ber 74AUP2G241GD XSON8	U has changed to XS	SON8.
74AUP2G241 v.6	20120606	Product data sheet	-	74AUP2G241 v.5
74AUP2G241 v.5	20111205	Product data sheet	-	74AUP2G241 v.4
74AUP2G241 v.4	20100913	Product data sheet	-	74AUP2G241 v.3
74AUP2G241 v.3	20090112	Product data sheet	-	74AUP2G241 v.2
74AUP2G241 v.2	20080219	Product data sheet	-	74AUP2G241 v.1
74AUP2G241 v.1	20061012	Product data sheet	-	-

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16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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